

## **Vishay Semiconductors**

# **Small Signal Switching Diode**

### Features

- Silicon Epitaxial Planar Diode
- · Low forward voltage drop
- High forward current capability
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
   FREE
- Halogen-free according to IEC 61249-2-21
  definition

## **Applications**

• High speed switch and general purpose use in computer and industrial applications



# **Mechanical Data**

Case: DO-35 Weight: approx. 125 mg Cathode Band Color: black Packaging Codes/Options: TR/10 k per 13" reel (52 mm tape), 50 k/box TAP/10 k per Ammopack (52 mm tape), 50 k/box

# Parts Table

Part	Ordering code	Type Marking	Remarks	
BAW27	BAW27-TR or BAW27-TAP	BAW27	Tape and Reel/Ammopack	

RoHS

### **Absolute Maximum Ratings**

#### T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		V <sub>RRM</sub>	75	V
Reverse voltage		V <sub>R</sub>	60	V
Peak forward surge current	t <sub>p</sub> = 1 μs	I <sub>FSM</sub>	4	A
Forward continuous current		١ <sub>F</sub>	600	mA
Average forward current	V <sub>R</sub> = 0	I <sub>FAV</sub>	300	mA
Power dissipation	l = 4 mm, T <sub>L</sub> = 45 °C	P <sub>tot</sub>	440	mW
Fower dissipation	$I = 4 \text{ mm}, \text{ T}_{L} \leq 25 ^{\circ}\text{C}$	P <sub>tot</sub>	500	mW

# **Thermal Characteristics**

 $T_{amb} = 25 \ ^{\circ}C$ , unless otherwise specified

Parameter	Test condition Symbol		Value	Unit
Thermal resistance junction to ambient air	$I = 4 \text{ mm}, T_L = \text{constant}$	R <sub>thJA</sub>	350	K/W
Junction temperature		Тj	175	°C
Storage temperature range		T <sub>stg</sub>	- 65 to + 175	°C

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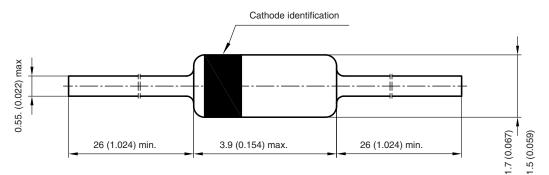


# **Electrical Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	I <sub>F</sub> = 10 mA	V <sub>F</sub>		670	750	mV
	I <sub>F</sub> = 50 mA	V <sub>F</sub>		800	850	mV
	I <sub>F</sub> = 200 mA	V <sub>F</sub>		950	1000	mV
	I <sub>F</sub> = 400 mA	V <sub>F</sub>		1120	1250	mV
Reverse current	V <sub>R</sub> = 60 V	I <sub>R</sub>			100	nA
neverse current	V <sub>R</sub> = 60 V, T <sub>j</sub> = 100 °C	I <sub>R</sub>			50	μA
Breakdown voltage	$I_R = 5 \ \mu A, \ t_p/T = 0.01,$ $t_p = 0.3 \ ms$	V <sub>(BR)</sub>	75			V
Diode capacitance	V <sub>R</sub> = 0, f = 1 MHz, V <sub>HF</sub> = 50 mV	CD			4	pF
Reverse recovery time	$I_F = I_R = 10 \text{ mA to } 100 \text{ mA},$ $i_R = 0.1 \text{ x } I_R$	t <sub>rr</sub>			6	ns

# Package Dimensions in millimeters (inches): DO-35



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